

Piezoresistive sensor differential pressure





PRODUCTS FEATURES

- Measurement range : 0~10/50/100/200 kPa
- Mems technology, solid-state reliability
- · Calibrated mV output
- Temperature compensated
- Working temperature: -30°C~+125°C
- Differential pressure



1. Technical specifications

1.1 Basic value

Table 1. Technical specifications

Specif	fications	Symbol	Min.	Тур.	Max	Unit	
				10, 50, 100, 200			
Pressure Range		Pop		1.45, 7.25, 14.5, 29			
Workin	g Voltage	Vs	<u> </u>	10	16	Vdc	
Workin	g Current	lo	_	6		mAdc	
StorageT	emperature	Tstg	-30	25	+125	°C	
Working T	Temperature	Topt	-20	_	+100	°C	
Bridge F	Resistance	RL	4.5	5	5.5	kΩ	
Offset/Z	ero Output	Voff	-1	0	+1	mV	
Sensitivity		Vfss	38.5	40	41.5	mV	
	10kPa	ΔV/ΔΡ	_	4	_		
	50kPa		_	0.8	_		
FS Output	100kPa		_	0.4	_	mV/kPa	
1 O Output	200kPa		_	0.2	_	1117/111 (4	
Lin	earity		-0.5		+0.5	%VFSS	
Hys	teresis		_	±0.15		%VFSS	
TCO(Temp. Coefficient of Offset)		TCVOFF	-1.0	_	+1.0	mV	
TCS(Temp. Coefficient of Span)		TCVFSS	-2.0	_	+2.0	%VFSS	
Response Time		TR	<u> </u>	2.5		ms	
Long-term Stability(1000h)			_	±0.5		%FS	

Note:

- 1. Sensor output is ratiometric within this specified excitation range. Operating the device above the specified excitation range may induce additional error due to sensor self-heating.
- 2. Full Scale Span (VFSS) is defined as the algebraic difference between the output voltage at full rated pressure and the output voltage at the minimum rated pressure.
- 3. Offset (Voff) is defined as the output voltage at the minimum rated pressure
- 4. Linearity: Output deviation from a straight line relationship with pressure, using end point method, over the specified pressure range.
- 5. Temperature Hysteresis: Output deviation at any temperature within the operating temperature range, after the temperature is cycled to and from the minimum or maximum operating temperature points, with zero differential pressure applied.
- 6. Pressure Hysteresis: Output deviation at any pressure within the specified range, when this pressure is cycled to and from the minimum or maximum rated pressure, at 25°C.
- 7. TcSpan: Output deviation at full rated pressure over the temperature range of 0 to 55°C, relative to 25°C.



- 8. TcOffset: Output deviation with minimum rated pressure applied, over the temperature range of 0 to 55°C, relative to 25°C
- 9. Response Time is defined as the time for the incremental change in the output to go from 10% to 90% of its final value when subjected to a specified step change in pressure
- 10. Offset stability is the product's output deviation when subjected to 1000 hours of Pulsed Pressure, Temperature Cycling with Test Condition.

Unless otherwise specified, measurements were taken on base of above testing condition.

1.2 Electronic performance, construction value and Environment condition

Table 2.

Electronic performance					
Power supply		≤16 VDC or 6.0 m ADC			
Inp	ut impedance	4kΩ~6kΩ			
Out	out impedance	4kΩ~6kΩ			
Insu	ulation resistor	100 MΩ, 100VDC			
O	ver Pressure	1.5x Rated Pressure			
	Const	ruction value			
S	Sensing die	Silicon			
Die	mounting glue	Silicone gel			
Leading wire		Gold wire			
Package housing		PPS			
Pin		Silver plated copper			
Net Weight		Approx. 5g			
	Environ	ment condition			
Or	ientation	Deviate 90° from any direction, zero change ≤ 0.05%FS			
	Shock	No change at 10gRMS, (20~2000)Hz condition			
	Impact	100g, 11ms			
Medium compatibility					
Pressure side	air or gas compatible with F	atible with FR4, silicone, silicone glue, metallic material and PPS.			
Reference side	dry air and non-corrosive gas compatible with PPS, silicon and silicone glue or epoxy, gold, aluminum and silver.				

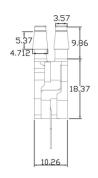


1.3 Test condition

Table 3. Test condition

Parameter	Value
Medium	gas
Medium Temp.	25±1°C
Environment Temp.	25±1°C
Shock	0.1g (1m/s2) Max
Humidity	(50%±10%) RH
Power supply	(10±0.005) VDC

2. Mechanical dimensions



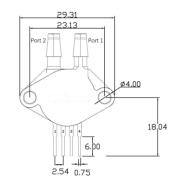


Figure 2.1. Mechanical dimension in mm

3. Pin connection and definition

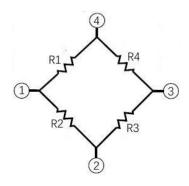


Figure 3.1. Circuit

i abie 5.	Pin	aetini	tion

Pin	1	2	3	4
Definition A	Vs+	Vo-	GND	Vo+
Definition B	GND	Vo+	VDD	Vo-

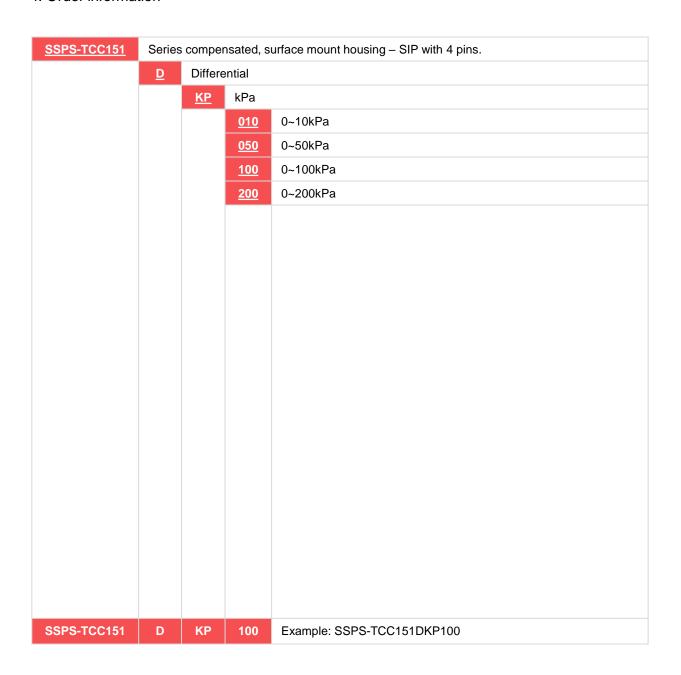
Definition A or B can be freely selected for connection

Table 6. Definition symbol

Symbol	Vs+	GND	Vo+	Vo-
Definition	Power+	Ground	Output+	Output-



4. Order information





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Development, production and supply of high-tech sensors